



FCC

RF Test Report

Product Name: Smart Phone

Model Number: HUAWEI RIO-L02, RIO-L02

Report No: SYBH(Z-RF)003062015-2002

FCC ID: QISRIO-L02

Reliability Laboratory of Huawei Technologies Co., Ltd.

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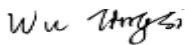


Applicant: Huawei Technologies Co., Ltd.
Address: Administration Building, Headquarters of Huawei Technologies Co., Ltd.,
Bantian, Longgang District, Shenzhen, 518129, P.R.C

Date of Receipt Sample: 2015-06-25
Start Date of Test: 2015-06-25
End Date of Test: 2015-06-30

Test Result: Pass

Approved by Senior Engineer:	2015-07-09	Liu Chunlin	
	Date	Name	Signature

Prepared by:	2015-07-09	maowenli	
	Date	Name	Signature



Modification Record

No.	Last Report No.	Modification Description
1		First report.

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1 General Information

1.1 Applied Standard

Applied Rules: 47 CFR FCC Part 02: 2014
47 CFR FCC Part 22: 2014
47 CFR FCC Part 27: 2014

Test Method: FCC KDB 971168 D01 Power Meas License Digital Systems v02r02

1.2 Test Location

Test Location 1: Reliability Laboratory of Huawei Technologies Co., Ltd.
Address: Administration Building, Headquarters of Huawei Technologies Co., Ltd.,
Bantian, Longgang District, Shenzhen, 518129, P.R.C

Test Location 2: BTL Laboratory
Address : No.3,Jinshagang 1st Road,ShiXia,Dalang Town,DongGuan,China.

1.3 Test Environment Condition

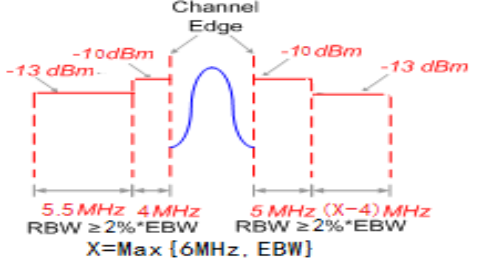
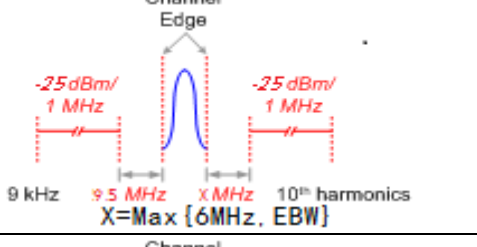
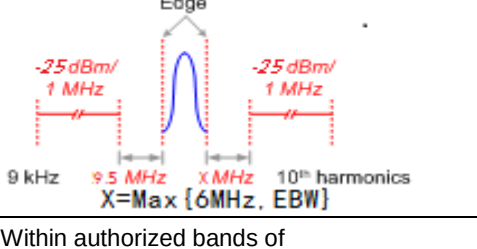
Ambient Temperature: 19.5 to 25 °C
Ambient Relative Humidity: 40 to 55 %
Atmospheric Pressure: Not applicable

2 Test Summary

2.1 Cellular Band (824-849 MHz paired with 869-894 MHz)

Test Item	FCC Rule No.	Requirements	Test Result	Verdict
Effective (Isotropic) Radiated Power Output Data	§2.1046, §22.913	ERP ≤ 7 W.	Appendix A	Pass
Peak-Average Ratio	---	---	Appendix B	N/T
Modulation Characteristics	§2.1047	Digital modulation	Appendix C	Pass
Bandwidth	§2.1049	OBW: No limit. EBW: No limit.	Appendix D	Pass
Band Edges Compliance	§2.1051, §22.917	≤ -13 dBm/1%*EBW, in 1 MHz bands immediately outside and adjacent to the frequency block.	Appendix E	Pass
Spurious Emission at Antenna Terminals	§2.1051, §22.917	≤ -13 dBm/100 kHz, from 9 kHz to 10 th harmonics but outside authorized operating frequency ranges.	Appendix F	Pass
Field Strength of Spurious Radiation	§2.1053, §22.917	≤ -13 dBm/100 kHz.	Appendix G	Pass
Frequency Stability	§2.1055, §22.355	≤ ±2.5ppm.	Appendix H	Pass
NOTE 1: For the verdict, the "N/A" denotes "not applicable", the "N/T" denotes "not tested".				

2.2 BRS&EBS Band (2570-2620 MHz paired with 2570-2620 MHz)

Test Item	FCC Rule No.	Requirements	Test Result	Verdict
Effective (Isotropic) Radiated Power Output Data	§2.1046, §27.50(h)	EIRP $\leq$ 2W	Appendix A	Pass
Peak-Average Ratio	---	---	Appendix B	N/T
Modulation Characteristics	§2.1047	Digital modulation	Appendix C	Pass
Bandwidth	§2.1049	OBW: No limit. EBW: No limit.	Appendix D	Pass
Band Edges Compliance	§2.1051, §27.53(m)		Appendix E	Pass
Spurious Emission at Antenna Terminals	§2.1051, §27.53(m)		Appendix F	Pass
Field Strength of Spurious Radiation	§2.1053, §27.53(m)		Appendix G	Pass
Frequency Stability	§2.1055, §27.54	Within authorized bands of operation/frequency block.	Appendix H	Pass

NOTE 1: For the verdict, the "N/A" denotes "not applicable", the "N/T" denotes "not tested".

3 Description of the Equipment under Test (EUT)

3.1 General Description

HUAWEI RIO-L02, RIO-L02 is subscriber equipment in the LTE/WCDMA/GSM system. The GSM/GPRS/EDGE frequency band includes GSM850 and GSM900 and DCS1800 and PCS1900. The HSPA+/UMTS frequency band is Band I and Band V and Band VIII. The LTE frequency band is B1 and B3 and B5 and B7 and B8 and B28 and B38 and B40. But only WCDMA B5 and LTE B5 and LTE B38 bands test data included in this report. The Mobile Phone implements such functions as RF signal receiving/transmitting, LTE/HSPA/UMTS and GSM/GPRS/EDGE protocol processing, voice, video MMS service, GPS, AGPS and WIFI etc. Externally it provides SIM card interface (it can also used as micro SD card interface), earphone port (to provide voice service) and USIM card interface. It also provides Bluetooth module to synchronize data between a PC and the phone, or to use the built-in modem of the phone to access the Internet with a PC, or to exchange data with other Bluetooth devices.

The differences between RIO-L01 and RIO-L02 are showed in the following table. Other parts of the mobile phone are the same, including the appearance, the antenna, Chipset, Bluetooth mode, Wifi mode, Adapter, Battery, Mainboard and so on.

	RIO-L01	RIO-L02
GSM four bands	the same	the same(SIM Card2 only support four GSM)
WCDMA bands	B1/B8	B1/B5/B8
LTE bands	B1/B3/B7/ B8/B20	B1/B3/B5/B7/ B8 /B28/B38/B40
FCC bands	GSM850/1900 LTE B7	GSM850/1900 W850 LTE B5/B7/B38
SIM card interface	ONE	TWO
External camera	the same	the same
internal camera	the same	the same
FLASH	the same	the same
Mainboard	the same	the same
PCB layout	the same	the same
Appearance	the same	the same
Bluetooth mode	the same	the same

WLAN mode	the same	the same
BT/ WLAN antenna	the same	the same
GSM/ WCDMA /LTE antenna	the same	the same
Adapter	the same	the same
Battery	the same	the same
Chipset	the same	the same
Memory	the same	the same
RF Parameter	The same RF Parameter in the same band	The same RF Parameter in the same band
Dimension	the same	the same
Main Frequency NV	The same NV in the same band	The same NV in the same band

NOTE: The WLAN data refer to SYBH(Z-RF)025042015-2002 of RIO-L01 WLAN report.

The Bluetooth data refer to SYBH(Z-RF)025042015-2004 of RIO-L01 Bluetooth report.

The Bluetooth BLE data refer to SYBH(Z-RF)025042015-2003 of RIO-L01 Bluetooth BLE report.

The LTE Band7 data refer to SYBH(Z-RF)025042015-2001 of RIO-L01 RF report.

The GSM850 and GSM1900 data refer to SYBH(Z-RF)025042015-2001 of RIO-L01 RF report.

3.2 EUT Identity

NOTE: Unless otherwise noted in the report, the functional boards installed in the units shall be selected from the below list, but not means all the functional boards listed below shall be installed in one unit.

3.2.1 Board

Board		
Description	Hardware Version	Software Version
Main Board	HL1RIOL02M	RIO-L02 C00B040

3.2.2 Sub-Assembly

Name	Manufacture	Description
Adapter	Huawei Technologies Co., Ltd.	Model: HW-050100U01 ~100-240V 50/60Hz 0.2A Output voltage: 5V  1A Rated Power: 5W
Adapter	Huawei Technologies Co., Ltd.	Model: HW-050100E01 ~100-240V 50/60Hz 0.2A Output voltage: 5V  1A Rated Power: 5W
Adapter	Huawei Technologies Co., Ltd.	Model: HW-050100B01 ~100-240V 50/60Hz 0.2A Output voltage: 5V  1A Rated Power: 5W
Adapter	Huawei Technologies Co., Ltd.	Model: HW-050100A01 ~100-240V 50/60Hz 0.2A Output voltage: 5V  1A Rated Power: 5W



3.2.3 Battery

Name	Manufacture	Description
Rechargeable Li-ion	Huawei Technologies Co., Ltd.	Battery Model: HB396481EBC Rated capacity: 3000mAh Nominal Voltage:  +3.8V Charging Voltage:  +4.35V

3.3 Technical Specification

Characteristics	Description	
Radio System Type	☒ UMTS ☒ LTE	
Supported Frequency Range	WCDMA850	Transmission (TX): 824 to 849 MHz
		Receiving (RX): 869 to 894 MHz
	LTE BAND5	Transmission (TX): 824 to 849 MHz
		Receiving (RX): 869 to 894 MHz
	LTE BAND38	Transmission (TX): 2570 to 2620 MHz
		Receiving (RX): 2570 to 2620 MHz
TX and RX Antenna Ports	TX & RX port:	1
	TX-only port:	0
	RX-only port:	1
Target TX Output Power	UMTS850 24dBm LTE BAND5: 23dBm LTE BAND38: 21.5dBm	
Supported Channel Bandwidth	UMTS system:	☒ 5 MHz
	LTE band 5	☒ 1.4 MHz, ☒ 3 MHz, ☒ 5 MHz, ☒ 10 MHz
	LTE band 38	☒ 5 MHz, ☒ 10 MHz, ☒ 15 MHz, ☒ 20 MHz
Designation of Emissions (Note: the necessary bandwidth of which is the worst value from the measured occupied bandwidths for each type of channel bandwidth configuration.)	UMTS850:	4M17F9W
	LTE BAND5:	1M09G7D (1.4 MHz QPSK modulation), 1M09W7D (1.4 MHz 16QAM modulation) 2M71G7D (3 MHz QPSK modulation), 2M70W7D (3 MHz 16QAM modulation) 4M51G7D (5 MHz QPSK modulation), 4M51W7D (5 MHz 16QAM modulation) 9M01G7D (10 MHz QPSK modulation), 9M01W7D (10 MHz 16QAM modulation)
	LTE BAND38:	4M51G7D (5 MHz QPSK modulation), 4M50W7D (5 MHz 16QAM modulation) 9M00G7D (10 MHz QPSK modulation), 9M00W7D (10 MHz 16QAM modulation) 13M5G7D (15 MHz QPSK modulation), 13M5W7D (15 MHz 16QAM modulation) 18M0G7D (20 MHz QPSK modulation), 18M0W7D (20 MHz 16QAM modulation)

4 General Test Conditions / Configurations

4.1 Test Modes

NOTE: The test mode(s) are selected according to relevant radio technology specifications.

Test Mode	Test Modes Description
UMTS/TM1	WCDMA system, QPSK modulation
UMTS/TM2	HSDPA system, QPSK modulation
UMTS/TM3	HSUPA system, QPSK modulation
LTE/TM1	LTE system, QPSK modulation
LTE/TM2	LTE system, 16QAM modulation

4.2 Test Environment

Environment Parameter	Selected Values During Tests	
Relative Humidity	Ambient	
Temperature	TN	Ambient
Voltage	VL	3.6V
	VN	3.8V
	VH	4.35V

NOTE: VL= lower extreme test voltage
VN= nominal voltage
VH= upper extreme test voltage
TN= normal temperature

4.3 Test Frequency

Test Mode	TX / RX	RF Channel		
		Low (L)	Middle (M)	High (H)
WCDMA850	TX	Channel 4132	Channel 4182	Channel 4233
		826.4MHz	836.4MHz	846.6MHz
	RX	Channel 4357	Channel 4407	Channel 4458
		871.4MHz	881.4MHz	891.6MHz

Test Mode	TX / RX	RF Channel		
		Low (B)	Middle (M)	High (T)
LTE Band 5	TX(1.4M)	Channel 20407	Channel 20525	Channel 20643
		824.7 MHz	836.5 MHz	848.3 MHz
	TX(3M)	Channel 20415	Channel 20525	Channel 20635
		825.5 MHz	836.5 MHz	847.5 MHz
	TX(5M)	Channel 20425	Channel 20525	Channel 20625
		826.5 MHz	836.5 MHz	846.5 MHz
	TX(10M)	Channel 20450	Channel 20525	Channel 20600
		829 MHz	836.5 MHz	844 MHz
	RX(1.4M)	Channel 2407	Channel 2525	Channel 2643
		869.7 MHz	881.5 MHz	893.3 MHz
	RX (3M)	Channel 2415	Channel 2525	Channel 2635
		870.5 MHz	881.5 MHz	892.5 MHz
	RX(5M)	Channel 2425	Channel 2525	Channel 2625
		871.5 MHz	881.5 MHz	891.5 MHz

Test Mode	TX / RX	RF Channel		
		Low (B)	Middle (M)	High (T)
	RX (10M)	Channel 2450	Channel 2525	Channel 2600
		874 MHz	881.5 MHz	889 MHz

Test Mode	TX / RX	RF Channel		
		Low (B)	Middle (M)	High (T)
LTE Band 38	TX(5M)	Channel 37775	Channel 38000	Channel 38225
		2572.5 MHz	2595 MHz	2617.5 MHz
	TX(10M)	Channel 37800	Channel 38000	Channel 38200
		2575 MHz	2595 MHz	2615 MHz
	TX(15M)	Channel 37825	Channel 38000	Channel 38175
		2577.5 MHz	2595 MHz	2612.5 MHz
	TX(20M)	Channel 37850	Channel 38000	Channel 38150
		2580 MHz	2595 MHz	2610 MHz
	RX(5M)	Channel 37775	Channel 38000	Channel 38225
		2572.5 MHz	2595 MHz	2617.5 MHz
	RX(10M)	Channel 37800	Channel 38000	Channel 38200
		2575 MHz	2595 MHz	2615 MHz
	RX(15M)	Channel 37825	Channel 38000	Channel 38175
		2577.5 MHz	2595 MHz	2612.5 MHz
	RX(20M)	Channel 37850	Channel 38000	Channel 38150
		2580 MHz	2595 MHz	2610 MHz

4.4 DESCRIPTION OF TESTS

4.4.1 Radiated Power and Radiated Spurious Emissions

Radiated spurious emissions are investigated indoors in a semi-anechoic chamber to determine the frequencies producing the worst case emissions. Final measurements for radiated power and radiated spurious emissions are performed on the 3 meter OATS per the guidelines of ANSI/TIA-603-C-2004. The equipment under test was transmitting while connected to its integral antenna and is placed on a wooden turntable 80cm above the ground plane and 3 meters from the receive antenna. The spectrum is scanned from the lowest frequency generated in the equipment up to a frequency including its 10th harmonic. The receive antenna height is adjusted between 1 and 4 meter height, the turntable is rotated through 360 degrees, and the EUT is manipulated through all orthogonal planes representative of its typical use to achieve the highest reading on the receive spectrum analyzer. Emissions are also investigated with the receive antenna horizontally and vertically polarized.

A portable or small unlicensed wireless device shall be placed on a non-metallic test fixture or other non-metallic support during testing. The supporting fixture shall permit orientation of the EUT in each of three orthogonal (x, y, z) axis positions such that emissions from the EUT are maximized. Measure the EUT maximum RF power and record the result.

A half-wave dipole is then substituted in place of the EUT. For emissions above 1GHz, a horn antenna is substituted in place of the EUT. The substitute antenna is driven by a signal generator with the level of the signal generator being adjusted to obtain the same receive spectrum analyzer level previously recorded from the spurious emission from the EUT. The power of the emission is calculated using the following formula:

$$P_d [\text{dBm}] = P_g [\text{dBm}] - \text{cable loss} [\text{dB}] + \text{antenna gain} [\text{dBd/dBi}]$$

Where, P_d is the dipole equivalent power, P_g is the generator output into the substitution antenna, and the antenna gain is the gain of the substitute antenna used relative to either a half-wave dipole (dBd) or an isotropic source (dBi). The substitute level is equal to $P_g [\text{dBm}] - \text{cable loss} [\text{dB}]$.

The calculated P_d levels are then compared to the absolute spurious emission limit of -13dBm which is equivalent to the required minimum attenuation of $43 + 10\log_{10}(\text{Power} [\text{Watts}])$.

Note: Reference test setup 3

4.4.2 Occupied Bandwidth

The occupied bandwidth, that is the frequency bandwidth such that, below its lower and above its upper frequency limits, the mean powers radiated are each equal to 0.5 percent of the total mean power radiated by a given emission shall be measured. The span of the analyzer shall be set to capture all products of the modulation process, including the emission skirts. The resolution bandwidth shall be set to as close to 1 percent of the selected span as is possible without being below 1 percent. The video bandwidth shall be set to 3 times the resolution bandwidth. Video averaging is not permitted. Where practical, a sampling detector shall be used since a peak or, peak hold, may produce a wider bandwidth than actual. The trace data points are recovered and are directly summed in linear terms. The recovered amplitude data points, beginning at the lowest frequency, are placed in a running sum until 0.5 percent of the total is reached and that frequency recorded. The process is repeated for the highest frequency data points. This frequency is recorded. The span between the two recorded frequencies is the occupied bandwidth.

Note: Reference test setup 1.

4.4.3 Spurious and Harmonic Emissions at Antenna Terminal

The level of the carrier and the various conducted spurious and harmonic frequencies is measured by means of a calibrated spectrum analyzer. The spectrum is scanned from the lowest frequency generated in the equipment up to a frequency including its 10th harmonic. On any frequency outside a licensee's frequency block, the power of any emission shall be attenuated below the transmitter power (P) by at least $43 + 10 \log(P)$ dB. Compliance with these provisions is based on the use of measurement instrumentation employing a resolution bandwidth of 1 MHz or greater. However, in the 1 MHz bands immediately outside and adjacent to the frequency block a resolution bandwidth of at least one percent of the emission bandwidth of the fundamental emission of the transmitter may be employed. The emission bandwidth is defined as the width of the signal between two points, one below the carrier center frequency and one above the carrier center frequency, outside of which all emission are attenuated at least 26 dB below the transmitter power.

Note: Reference test setup 1.

4.4.4 Peak-Average Ratio

A peak to average ratio measurement is performed at the conducted port of the EUT. For WCDMA signals, the spectrum analyzers Complementary Cumulative Distribution Function (CCDF) measurement profile is used to determine the largest deviation between the average and the peak power of the EUT in a given bandwidth. The CCDF curve shows how much time the peak waveform spends at or above a given average power level. The percent of time the signal spends at or above the level defines the probability for that particular power level. For GSM signals, an average and a peak trace are used on a spectrum analyzer to determine the largest deviation between the average and the peak power of the EUT in a bandwidth greater than the emission bandwidth. The traces are generated with the spectrum analyzer set to zero span mode.

Note: Reference test setup 1.

4.4.5 Frequency Stability / Temperature Variation

Frequency stability testing is performed in accordance with the guidelines of ANSI/TIA-603-C-2004. The frequency stability of the transmitter is measured by:

- a.) **Temperature:** The temperature is varied from -30°C to +50°C in 10°C increments using an environmental chamber.
- b.) **Primary Supply Voltage:** The primary supply voltage is varied from 85% to 115% of the nominal value for non hand-carried battery and AC powered equipment. For hand-carried, battery-powered equipment, primary supply voltage is reduced to the battery operating end point which shall be specified by the manufacturer.

Specification – The frequency stability shall be sufficient to ensure that the fundamental emission stays within the authorized frequency block. The frequency stability of the transmitter shall be maintained within $\pm 0.00025\%$ (± 2.5 ppm) of the center frequency.

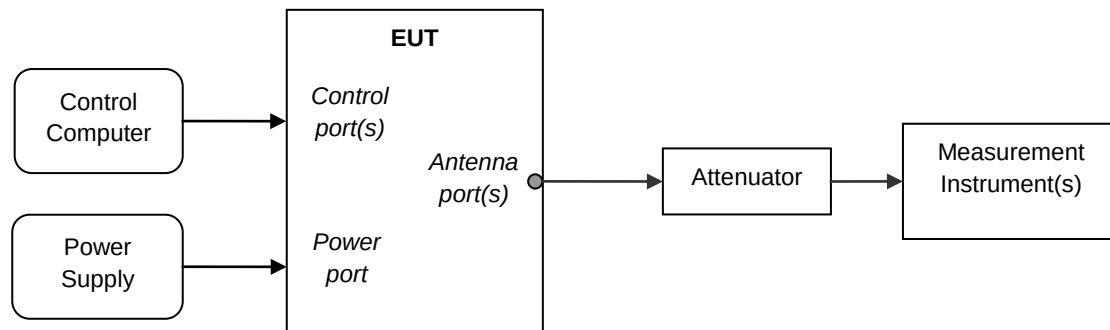
Time Period and Procedure:

1. The carrier frequency of the transmitter is measured at room temperature (20°C to provide a reference).
2. The equipment is turned on in a “standby” condition for fifteen minutes before applying power to the transmitter. Measurement of the carrier frequency of the transmitter is made within one minute after applying power to the transmitter.
3. Frequency measurements are made at 10°C intervals ranging from -30°C to +50°C. A period of at least one half-hour is provided to allow stabilization of the equipment at each temperature level.

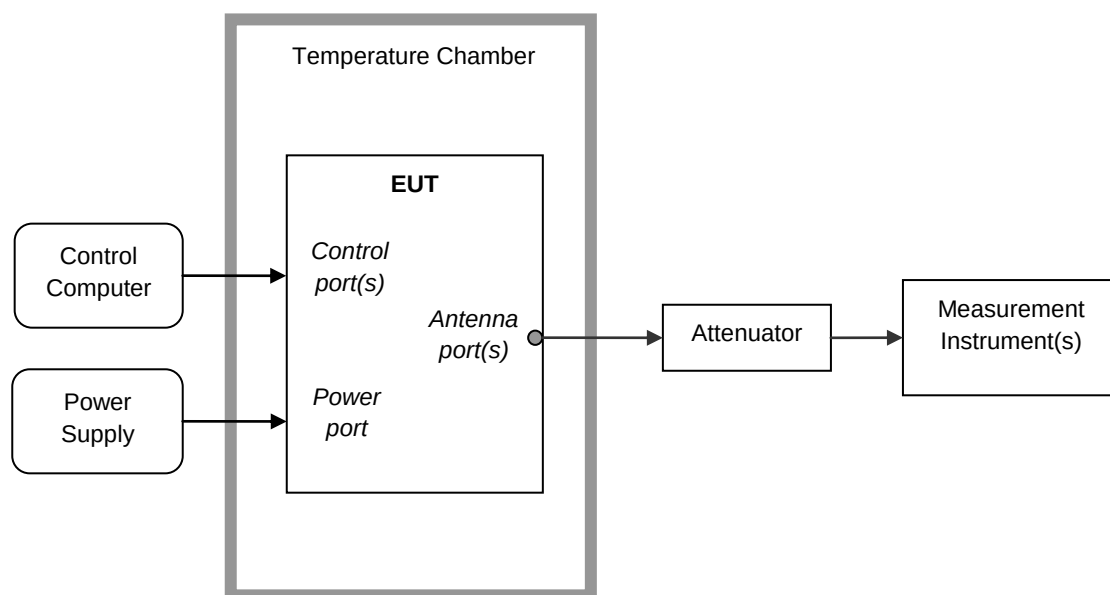
Note: Reference test setup 2.

4.5 Test Setups

4.5.1 Test Setup 1



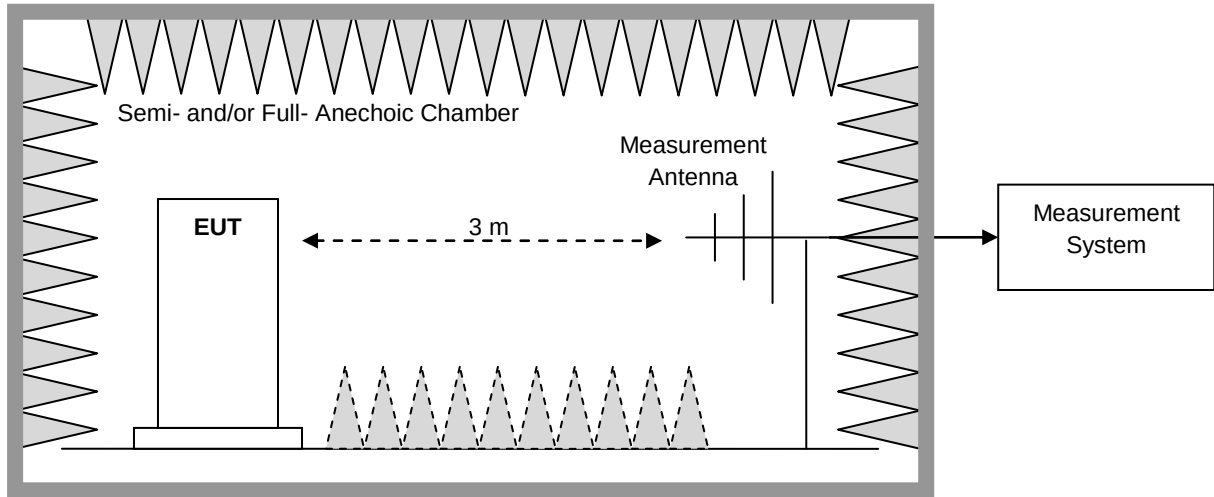
4.5.2 Test Setup 2



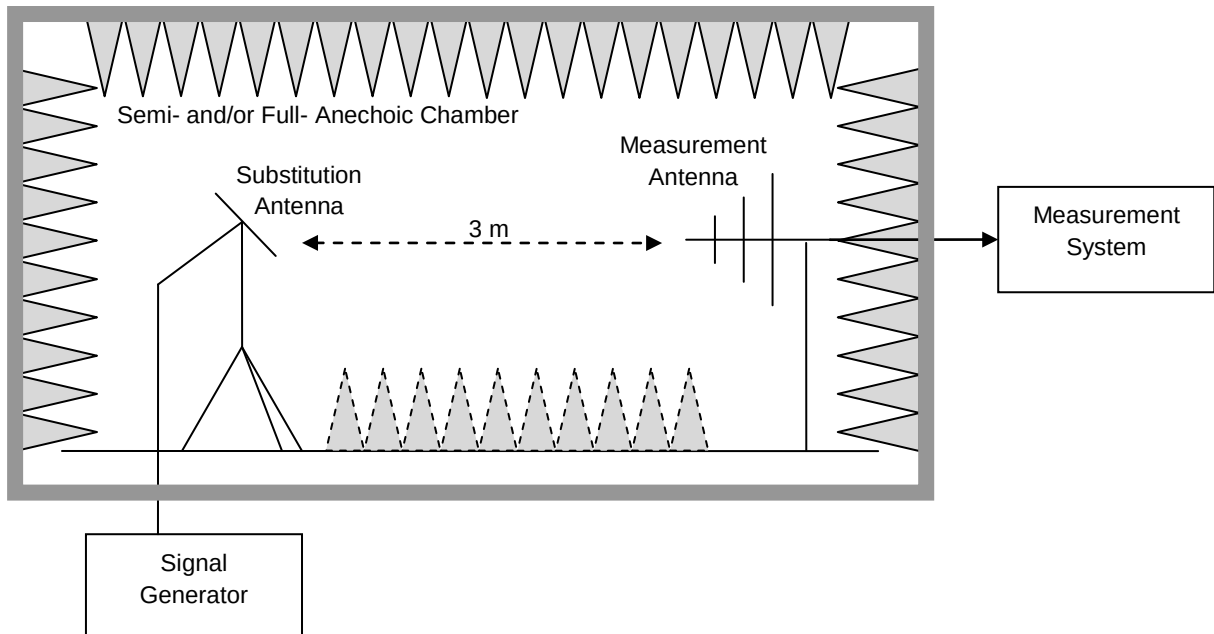
4.5.3 Test Setup 3

NOTE: Effective radiated power (ERP) refers to the radiation power output of the EUT, assuming all emissions are radiated from half-wave dipole antennas.

4.5.3.1 Step 1: Pre-test



4.5.3.2 Step 2: Substitution method to verify the maximum ERP



4.6 Test Conditions

Test Case		Test Conditions	
Transmit Output Power Data	Average Power, Total	Test Env.	Ambient Climate & Rated Voltage
		Test Setup	Test Seup 1
		RF Channels (TX)	L, M, H (L= low channel, M= middle channel, H= high channel)
		Test Mode	UMTS/TM1,LTE/TM1,LTE/TM2
	Average Power, Spectral Density (if required)	Test Env.	Ambient Climate & Rated Voltage
		Test Setup	Test Seup 1
		RF Channels (TX)	L, M, H (L= low channel, M= middle channel, H= high channel)
		Test Mode	UMTS/TM1,LTE/TM1,LTE/TM2
Peak-to-Average Ratio (if required)		Test Env.	Ambient Climate & Rated Voltage
		Test Setup	Test Seup 1
		RF Channels (TX)	L, M, H (L= low channel, M= middle channel, H= high channel)
		Test Mode	UMTS/TM1,LTE/TM1,LTE/TM2
Modulation Characteristics		Test Env.	Ambient Climate & Rated Voltage
		Test Setup	Test Seup 1
		RF Channels (TX)	M (L= low channel, M= middle channel, H= high channel)
		Test Mode	UMTS/TM1,LTE/TM1,LTE/TM2
Bandwidth	Occupied Bandwidth	Test Env.	Ambient Climate & Rated Voltage
		Test Setup	Test Seup 1
		RF Channels (TX)	L, M, H (L= low channel, M= middle channel, H= high channel)
		Test Mode	UMTS/TM1,LTE/TM1,LTE/TM2
	Emission Bandwidth (if required)	Test Env.	Ambient Climate & Rated Voltage
		Test Setup	Test Seup 1
		RF Channels (TX)	L, M, H (L= low channel, M= middle channel, H= high channel)
		Test Mode	UMTS/TM1,LTE/TM1,LTE/TM2
Band Edges Compliance		Test Env.	Ambient Climate & Rated Voltage
		Test Setup	Test Seup 1
		RF Channels (TX)	L, H (L= low channel, M= middle channel, H= high channel)
		Test Mode	UMTS/TM1,LTE/TM1,LTE/TM2
Spurious Emission at Antenna Terminals		Test Env.	Ambient Climate & Rated Voltage
		Test Setup	Test Seup 1
		RF Channels	L, M, H

Test Case	Test Conditions	
	(TX)	(L= low channel, M= middle channel, H= high channel)
	Test Mode	UMTS/TM1,LTE/TM1,LTE/TM2
Field Strength of Spurious Radiation	Test Env.	Ambient Climate & Rated Voltage
	Test Setup	Test Seup 3
	Test Mode	UMTS/TM1/TM2/TM3,LTE/TM1,LTE/TM2 NOTE: If applicable, the EUT conf. that has maximum power density (based on the equivalent power level) is selected.
	RF Channels (TX)	L, M, H (L= low channel, M= middle channel, H= high channel)
Frequency Stability	Test Env.	(1) -30 °C to +50 °C with step 10 °C at Rated Voltage; (2) VL, VN and VH of Rated Voltage at Ambient Climate.
	Test Setup	Test Seup 2
	RF Channels (TX)	L, M, H (L= low channel, M= middle channel, H= high channel)
	Test Mode	UMTS/TM1,LTE/TM1,LTE/TM2

5 Main Test Instruments

Equipment Name	Manufacturer	Model	Serial Number	Cal Date	Cal- Due
Power supply	KEITHLEY	2303	A120714713	2014-08-07	2016-08-06
Wireless Communication Test set	Agilent	N4010A	MY49081592	2014-11-04	2015-11-03
Universal Radio Communication Tester	R&S	CMU200	123299	2014-11-04	2015-11-03
Spectrum Analyzer	Agilent	N9020A	MY52090652	2014-07-11	2015-08-10
Universal Radio Communication Tester	R & S	CMW500	126854	2015-02-13	2016-02-12
Spectrum Analyzer	Agilent	E4440A	MY48250119	2014-07-11	2015-08-10
Signal Analyzer	R&S	FSQ31	200021	2014-11-04	2015-11-03
Spectrum Analyzer	Agilent	N9030A	MY49431698	2014-11-04	2015-11-03
Temperature Chamber	WEISS	WKL64	56246002940010	2015-02-13	2016-02-12
Signal generator	Agilent	E8257D	MY49281095	2014-11-04	2015-11-03
Vector Signal Generator	R&S	SMU200A	104162	2014-11-04	2015-11-03
Spectrum analyzer	R&S	FSU3	200474	2014-11-04	2015-11-03
Spectrum analyzer	R&S	FSU43	100144	2014-11-04	2015-11-03
Double-Ridged Waveguide Horn Antenna (1G~18GHz)	R&S	HF907	100391	2013-12-21	2015-12-20
Trilog Broadband Antenna (30M~3GHz)	SCHWARZB ECK	VULB 9163	9163-521	2013-12-21	2015-12-20
Pyramidal Horn Antenna(18GHz-26-5GHz)	ETS-LINDG REN	3160-09	5140299	2015-01-05	2017-01-04
Artificial Mains Network	R&S	ENV4200	100134	2014-11-04	2015-11-03
Artificial Mains Network	R&S	ENV216	100382	2014-11-04	2015-11-03
Power Detecting & Sampling Unit	R&S	OSP-B157	19709DD	2014-09-08	2015-09-07
Signal Generator	Agilent	E4438C	MY47271904	2014-10-28	2015-10-27



Description	TYPE	SERIES NUMBER	MANUFACTURE	CAL DUE DATE
EXA Spectrum Analyzer	N9010A	MY5052044	Agilent	Mar.28,2016
Microwave Preamplifier With Adaptor	EMC012645B	980221	EMC INSTRUMENT	Oct.22,2015
Amplifier	8449B	3008A02274	Agilent	Mar.28,2016
Double Ridged Guide Antenna	3115	00075846	ETS.LINDGREN	Mar.28,2016
Antenna	VULB9160	9160-3231	SCHWARZBEC K	Mar.28,2016
controller	SC100	9163-235	CT	N/A

6 Measurement Uncertainty

For a 95% confidence level ($k = 2$), the measurement expanded uncertainties for defined systems, in accordance with the recommendations of ISO 17025 as following:

Test Item		Extended Uncertainty
Transmit Output Power Data	Power [dBm]	U = 0.39 dB
Bandwidth	Magnitude [%]	U = 0.2%
Band Edge Compliance	Disturbance Power [dBm]	U = 2.0 dB
Spurious Emissions, Conducted	Disturbance Power [dBm]	U = 2.0 dB
Field Strength of Spurious Radiation	ERP [dBm]	For 3 m Chamber: U = 4.6 dB (30 MHz to 1GHz) U = 3.0 dB (above 1 GHz) For 10 m Chamber: U = 4.6 dB (30 MHz to 1GHz) U = 3.0 dB (above 1 GHz)
Frequency Stability	Frequency Accuracy [ppm]	U = 0.21 ppm

END